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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/749,599	12/31/2003	Kazuaki Ejiri	IGM-02001	8531	
7:	590 04/27/2005		EXAMINER		
Patent Group			LEE, CALVIN		
Choate, Hall &	Stewart				
Exchange Place	•	ART UNIT	PAPER NUMBER		
53 State Street		2818			
Boston, MA (02109-2804		DATE MAILED: 04/27/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

				XI			
		Application No.	Applicant(s)				
Office Action Summary		10/749,599	EJIRI, KAZUAKI	•			
		Examiner	Art Unit				
		Lee, Calvin	2818				
The MAILING DATE Period for Reply	of this communication ap	pears on the cover sheet with the	correspondence address				
THE MAILING DATE OF - Extensions of time may be available after SIX (6) MONTHS from the mile. - If the period for reply specified about 1 NO period for reply is specified about 1 Failure to reply within the set or expenses.	THIS COMMUNICATION. It under the provisions of 37 CFR 1. ailing date of this communication. to is less than thirty (30) days, a rep blove, the maximum statutory period tended period for reply will, by statut ter than three months after the mailir	LY IS SET TO EXPIRE 3 MONTH 136(a). In no event, however, may a reply be a ply within the statutory minimum of thirty (30) do will apply and will expire SIX (6) MONTHS fro e, cause the application to become ABANDON ing date of this communication, even if timely fil	imely filed ays will be considered timely. m the mailing date of this communication. ED (35 U.S.C. § 133).				
Status							
1) Responsive to com	nunication(s) filed on 4/7/	05 (Election).					
2a) This action is FINAL	2b)⊠ Thi	s action is non-final.					
		ance except for formal matters, p					
closed in accordance	e with the practice under	Ex parte Quayle, 1935 C.D. 11,	153 O.G. 213.				
Disposition of Claims							
4)⊠ Claim(s) <u>1-16</u> is/are	pending in the application	1.					
4a) Of the above cla	im(s) <u>14-16</u> is/are withdra	wn from consideration.					
5) Claim(s)is/a	Claim(s) is/are allowed.						
· · · · · · · · · · · · · · · · · · ·	Claim(s) <u>1-13</u> is/are rejected.						
7) Claim(s) is/a							
8) Claim(s) are	subject to restriction and/	or election requirement.					
Application Papers							
9) ☐ The specification is of	•						
10) ☐ The drawing(s) filed	on is/are: a)□ acc	cepted or b) objected to by the	Examiner.				
• • • • • • • • • • • • • • • • • • • •		e drawing(s) be held in abeyance. S					
·		ction is required if the drawing(s) is o					
11) The oath or declarat	ion is objected to by the E	xaminer. Note the attached Office	e Action or form PTO-152.				
Priority under 35 U.S.C. § 11	9						
a)⊠ All b)□ Some * 1.⊠ Certified copi 2.□ Certified copi 3.□ Copies of the application from	c) None of: es of the priority documen es of the priority documen certified copies of the priority om the International Burea	ts have been received in Applica ority documents have been receiv	tion No ved in this National Stage				
·							
Attachment(s)		П.					
 Notice of References Cited (PT Notice of Draftsperson's Paten 		4) ∭ Interview Summai Paper No(s)/Mail I					
3) Information Disclosure Statemer Paper No(s)/Mail Date 1/26/04.	ent(s) (PTO-1449 or PTO/SB/08)		Patent Application (PTO-152)				

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OFFICE ACTION

Response to Election

1. The election of claims 1-13, received on March 21, 2005, is acknowledged. As a result, claims 14-16 are withdrawn from further consideration.

Claim Rejections - 35 U.S.C. § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office Action:
- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claim 1, 4-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sachan et al Sachan et al (US 6,617,717) discloses a chemical mechanical polishing method for polishing a low-k material insulating layer formed on a semiconductor wafer, comprising of:

 -preparing an aqueous abrasive slurry composed of a water component, an abrasive component, a first additive, and a second to additive for adding acidity to the aqueous abrasive slurry; wherein the first additive comprises a hydroxide selected from the group consisting of ammonium hydroxide NH₃OH and potassium hydroxide KOH, and the second additive comprises an acid from the group comprising at least aqueous oxalic acid (C₂H₂O₄) solution [Example 2 in col. 5]; wherein at most 2 % of the hydroxide is contained in the slurry
- -feeding the aqueous abrasive slurry to a rotating polishing pad [col. 4, ln.60];
- -applying and pressing the insulating layer onto the polishing pad within a range between approximately 3psi and approximately 5psi [col. 5, ln.28].
- a) Sachan et al is silent about "for making the low-k material insulating layer of said semiconductor wafer hydrophilic in nature." The examiner notes that such functional recitation has not been given patentable weight because it is narrative in form unless it must be expressed as a "means" for performing the specified function, as set forth in 35 USC 112, 6th paragraph, and must be supported by recitation in the claim of sufficient structure to warrant the presence of the functional language. In re Fuller, 1929 C.D. 172, 388 O.G. 279.
- c) In re claims 5 and 8, Sachan et al suggests, "all slurries in this example containing 10% colloidal silica abrasive (Klebosol 1498), were at a pH of 10.5" [col. 4, ln.65], but not 20% colloidal silica. Moreover, Sachan et al does not suggest explicitly that the slurry exhibits a pH falling in a range between approximately 3 to 6.

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Kazuaki ЕЛПІ

It would have been obvious to one having skills in the art have modified the weight percent of the colloid silica and/or the pH level of the slurry in Sachan et al' process, and thus arrive at the claimed weight percent and the pH level because one would adjust the potassium hydroxide to obtain a desired pH level and/or weight percent of the colloidal silica.

- 4. Claim 2-3 and 9-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sachan et al (US 6,617,717) in view of Konno et al (US 2004/0162011).
- a) In re claims 2-3, 9, and 13, Sachan et al suggests the insulating layer of SiO₂ (beside disclosing, "copper interconnects coupled with low-k dielectrics") Konno et al discloses, "silicon oxide dielectrics of low dielectric constant ... an MSQ methyl silsesquioxane film ..." [¶ 0133]

It would have been obvious to one with ordinary skill in the art to modify the low-k insulating layer of *Sachan et al* by utilizing claimed low-k materials, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. *In re Leshin*, 125 SUPQ 416.

b) In re claims 10-12, Sachan et al is silent about washing and/or rinsing step. Konno et al discloses, "after completion of the polishing treatment, ... the removal of the abrasive grains can be conducted by an ordinary cleaning method ... water" [¶ 0122].

It would have been obvious to one with ordinary skill in the art to modify the process of Sachan et al by utilizing an extra washing/rinsing step for the purpose of completely removing unwanted debris/species absorbed on the polished surface [¶ 0123].

Contact Information

5. Any inquiry concerning this communication from the Examiner should be directed to Calvin Lee at (571) 272-1896 on Mondays thru Thursdays 6:30-4:30PM. If attempts to reach the examiner by telephone are unsuccessful, Art Unit 2818's Supervisory Patent Examiner David Nelms can be reached at (571) 272-1787. The fax phone number for the organization (where this application is assigned to) is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system at http://pair-direct.uspto.gov. Should you have questions on access to the PAIR system, contact the Electronic Business Center at (866) 217-9197.

CL

David Neims Supervisory Patent Examiner Technology Center 2800

Dated: April 26, 2005